## NSN 5961-01-127-7853

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-127-7853 **Inclosure Material:** Ceramic **Overall Length:** 0.785 inches **Overall Height:** 0.365 inches **Overall Width:** 0.310 inches **Component Name And Quantity:** 8 semiconductor device diode **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 40.0 regulator voltage all semiconductor device diode **Current Rating Per Characteristic:** 350.00 milliamperes source cutoff current horsepower metric all semiconductor device diode **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Precious Material And Location:** Terminals gold **Precious Material:** Gold **Terminal Type And Quantity:** 16 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: